DFB13XX000YY200MFXXX Preliminary

Fiber Coupled Distributed-Feedback Laser Diode



Features:

- Output power 200mW ex-fiber in 1270-1330nm range
- InAs/GaAs Quantum Dot based diode laser
- · Mode-hop free continious tuning
- · Individual burn-in and thermal cycling screening
- · Proprietary mirror coating technology enabling high reliability
- Built-in monitor photodiode
- Fiber-spliced optical isolator (optional)
- 900um loose tube on fiber (optional)

Applications:

- Coherent communication (O-band)
- Fiber sensing
- LiDAR
- · Quantum & nonlinear optics
- Spectroscopy

Recommended Operating Conditions				
@ CW, the case is mounted on room temperature heatsink				
Parameter	Min.	Тур.	Max.	Unit
Chip Temperature	20	25*	40	°C
Forward Current		1000	1300	mA
Output Power**	100		200	mW

^{*} in some cases may vary depending on the selected wavelength

^{**} kink-free and mode-hop-free over the specified power range (min - max)

Characteristics				
@ CW, 25°C*, 1000mA				
Parameter	Min.	Тур.	Max.	Unit
Forward Current @ 200mW			1300	mA
Forward Voltage @ 200mW		1.6	2.4	V
Threshold Current		80	130	mA
Monitor Photodiode Current		350		μA
Monitor Photodiode Responsivity		1.5		μA/mW
Peak Wavelength** (chosen by customer)	1270		1330	nm
Peak Wavelength Tolerance			±3	nm
Wavelength Temperature Tunability		100		pm/°C
Wavelength Current Tunability		0.6		pm/mA
Side-Mode Suppression Ratio (SMSR)	35	45		dB
Polarisation Extinction Ratio (PER)	12	15		dB
Polarisation		TE		

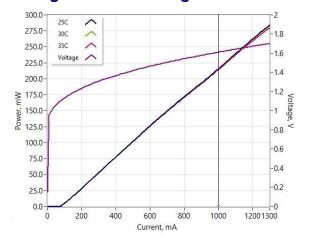
 $[\]ensuremath{^*}$ in some cases may vary in 20-40°C range depending on the selected wavelength

^{**} reachable within wavelength tolerance at power 200mW; performance at wavelength range edges may require minor specification adjustments

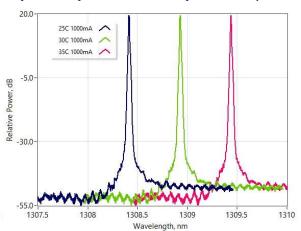


Typical Performance (for reference only)

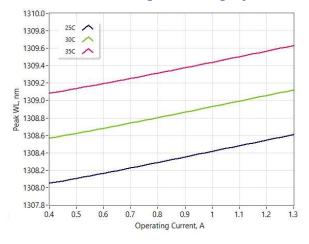
Light Current Voltage Characteristics



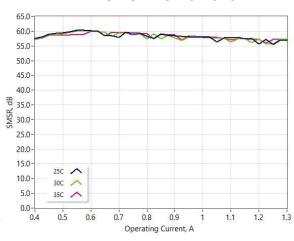
Optical Spectra vs Temperature (res. 5pm)



Peak Wavelength Tuning by Current



SMSR vs Current

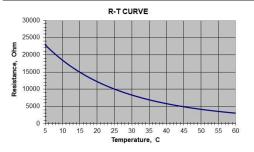


Absolute Maximum Ratings			
Parameter	Min	Max	Unit
Forward Current		1500	mA
Reverse Voltage		2	V
TEC Current		3	Α
TEC Voltage		4	V
Chip Operating Temperature	5	50	°C
Case Operating Temperature	0	70	°C
Monitor Photodiode Bias Voltage		5	V
Pin Soldering Temperature (max 10 sec, max case temperature 120°C)		300	°C
Storage Temperature	-40	85	°C
Fiber Band Radius	3		cm

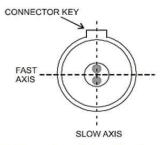


Specification

Thermistor specification			
Parameters	Value	Unit	
Туре	NTC		
Resistance @ 25°C	10±0.1	kOhm	
Beta 25-85°C	3435±1%	K	

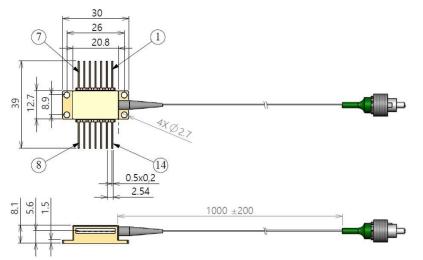


Fiber specification			
Parameters	Value	Value	Unit
Fiber Type	HI1060	PM1310	
Numerical Aperture (Typical)	0.14	0.12	
Cut-off Wavelength	920±50	1200±70	nm
Mode-Field (core) Diameter	6.2±0.3 @1060nm	9.3±0.5 @1300nm	μm
Cladding Diameter	125±1	125±1	μm
Coating (buffer) Diameter	245±15	245±15	μm
Loose Tube Diameter (optional)	900	900	μm
Connector	FC/APC	FC/APC	
Key	narrow	narrow	



The output light is polarized along the slow axis of PM fiber.

Dimensions (in mm)



Pin identification:

1. TEC "+"

2. Thermistor

3. Monitor PD anode (Bias "-")

4. Monitor PD cathode (Bias "+")

5. Thermistor

6. -

7. -8. -

9 -

10. LD anode ("+")

11. LD cathode ("-")

12. -

13. Case

14. TEC "-"



Specification

Innolume GmbH Konrad-Adenauer-Allee 11 44263 Dortmund, Germany

Safety and Operating Instructions

The light emitted from this device is invisible and can be harmful to the human eye. Avoid looking directly into the fiber connector when the device is in operation. Proper laser safety eyewear must be worn during operation with open connector. Absolute Maximum Ratings may be applied to the device for short period of time only. Exposure to maximum ratings for extended period of time or exposure to more than one maximum rating may cause damage or affect the reliability of the device. Operating the device outside of its maximum ratings may cause device failure or a safety hazard. Power supplies used with the component must be employed such that the maximum forward current cannot be exceeded.

A proper heatsink for the device on thermal radiator is required. The device must be mounted on radiator with 4 screws (bolt down in X-style fashion with initial torque set to 0.075Nm and final X-style bolt down at 0.15Nm) or with clamps. The deviation from flatness of radiator surface must be less than 0.05mm. It's recommended using of Indium foil or thermal conductive and soft material between bottom of the case and heatsink for thermal interface. It's undesirable to use thermal grease for this. Avoid back reflection to the device. It may give impact on the device performance in aspects of spectrum and power stability. It also may cause fatal facet damage. Using of optical isolators is highly recommended to block back reflection. Do not pull the fiber. Do not bend a fiber with a radius smaller than 3 cm. Fiber tip should always be protected from any contamination or damage during the process of installation. After removing the dust-preventing cap covered at fiber tip, carefully clean fiber tip by wiping through one direction using optical lens cleaning paper or cotton swab dabbed with Iso-Propanol or Ethyl alcohol. Operate the device with clean fiber connector only.

Electrostatic discharge is the primary cause of unexpected product failure. Take extreme precaution to prevent ESD. During device installation, ESD protection has to be maintained - use wrist straps, grounded work surfaces and rigorous antistatic techniques when handling the product.











Part-number Identification

DFB1270000HI0200MFXXX -> 200mW output power at 1270nm peak wavelength, HI-1060 fiber, with built-in monitor photodiode

DFB1330D50PM0200MFXXX -> 200mW output power at 1330.5nm peak wavelength, PM1310 fiber, with built-in monitor photodiode

DFB1330D53PM0200MFLXX -> 200mW output power at 1330.53nm peak wavelength, PM1310 fiber, with built-in monitor photodiode and fiber loose tube

NOTE: Innolume product specifications are subject to change without notice